

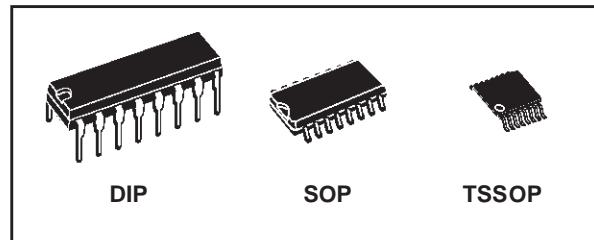
## QUAD BILATERAL SWITCH

- HIGH SPEED:  
 $t_{PD} = 13\text{ns}$  (TYP.) at  $V_{CC} = 6\text{V}$
- LOW POWER DISSIPATION:  
 $I_{CC} = 1\mu\text{A}$ (MAX.) at  $V_{CC} = 5\text{V}$
- LOW "ON" RESISTANCE:  
120 $\Omega$  TYP. ( $V_{CC} - V_{EE} = 2\text{V}$ )  
50 $\Omega$  TYP. ( $V_{CC} - V_{EE} = 4.5\text{V}$ )  
35 $\Omega$  TYP. ( $V_{CC} - V_{EE} = 9\text{V}$ )
- WIDE ANALOG INPUT VOLTAGE RANGE  $\pm 6\text{v}$
- LOW CROSSTALK BETWEEN SWITCHES
- FAST SWITCHING
- SINE WAVE DISTORTION:  
0.020 at  $V_{CC} - V_{EE} = 9\text{V}$
- HIGH NOISE IMMUNITY:  
 $V_{NIH} = V_{NIL} = 28\%$   $V_{CC}$  (MIN.)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 4316

### DESCRIPTION

The M74HC4316 is an high speed CMOS QUAD BILATERAL SWITCH fabricated with silicon gate C<sup>2</sup>MOS technology.

This device has four independent analogue switches. Each switch has two input/output terminals (nI/O, nO/I) and an active high select input (nC).



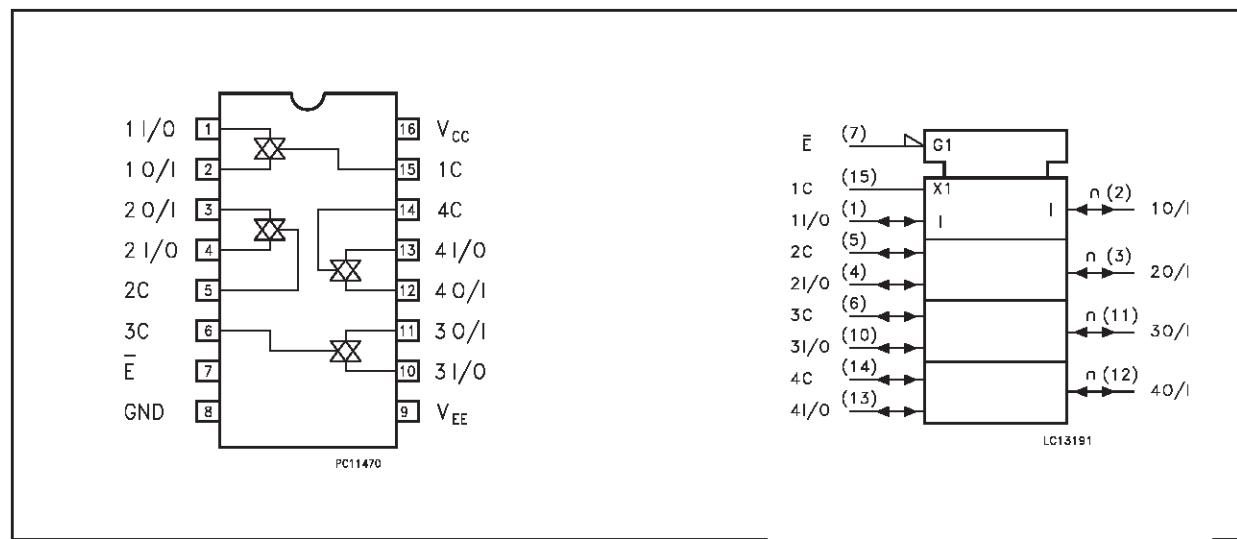
### ORDER CODES

PACKAGE	TUBE	T & R
DIP	M74HC4316B1R	
SOP	M74HC4316M1R	M74HC4316RM13TR
TSSOP		M74HC4316TTR

When the enable input is high, all four analog switches are off. The supply voltage for the digital signals applied to  $V_{CC}$  and GND must be within the range 0 to 6 V. The voltage swing on the analogue Inputs/Outputs can be between  $V_{CC}$  (positive limit) and  $V_{EE}$  (negative limit). The voltage between  $V_{CC}$  and  $V_{EE}$  must not exceed 12V.

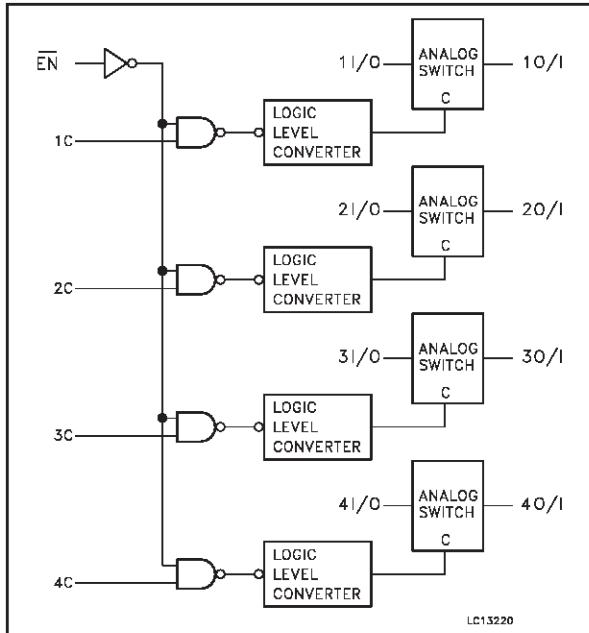
All inputs are equipped with protection circuits against static discharge and transient excess voltage.

### PIN CONNECTION AND IEC LOGIC SYMBOLS



# M74HC4316

## LOGIC DIAGRAM



## PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 4, 10, 13	1 to 4 I/O	Independent Inputs/Outputs
2, 3, 11, 12	1 to 4 O/I	Independent Outputs/Inputs
7	$\bar{E}$	Enable Inputs (Active LOW)
15, 5, 6, 14	1C to 4C	Enable Inputs (Active HIGH)
9	$V_{EE}$	Negative Supply Voltage
8	GND	Ground (0V)
16	$V_{CC}$	Positive Supply Voltage

## TRUTH TABLE

$\bar{E}$	C	SWITCH FUNCTION
L	H	ON
L	L	OFF
H	X	OFF

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	-0.5 to +7	V
$V_{CC} - V_{EE}$	Supply Voltage	-0.5 to +13	V
$V_I$	Control Input Voltage	-0.5 to $V_{CC} + 0.5$	V
$V_{I/O}$	Switch Input/Output Voltage	$V_{EE} - 0.5$ to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current	$\pm 20$	mA
$I_{OK}$	DC Output Diode Current	$\pm 20$	mA
$I_O$	DC Output Source Sink Current Per Output Pin	$\pm 25$	mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or Ground Current	$\pm 50$	mA
$P_D$	Power Dissipation	500(*)	mW
$T_{stg}$	Storage Temperature	-65 to +150	°C
$T_L$	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

(\*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	2 to 12	V
$V_{EE}$	Supply Voltage	-6 to 0	V
$V_{CC} - V_{EE}$	Supply Voltage	2 to 12	V
$V_I$	Input Voltage	0 to $V_{CC}$	V
$V_{I/O}$	Switch I/O Voltage	0 to $V_{CC}$	V
$T_{op}$	Operating Temperature	-55 to 125	°C
$t_r, t_f$	Input Rise and Fall Time	$V_{CC} = 2.0V$	0 to 1000
		$V_{CC} = 4.5V$	0 to 500
		$V_{CC} = 6.0V$	0 to 400

## DC SPECIFICATIONS

Symbol	Parameter	Test Condition			Value						Unit	
		$V_{CC}$ (V)	$V_{EE}$ (V)		$T_A = 25^\circ C$			$-40 \text{ to } 85^\circ C$		$-55 \text{ to } 125^\circ C$		
					Min.	Typ.	Max.	Min.	Max.	Min.		
$V_{IHC}$	High Level Control Input Voltage	2.0			1.5			1.5		1.5	V	
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
$V_{ILC}$	Low Level Control Input Voltage	2.0					0.5		0.5		V	
		4.5					1.35		1.35			
		6.0					1.8		1.8			
$R_{ON}$	ON Resistance	4.5	GND	$V_I = V_{IHC}$ $V_{I/O} = V_{CC}$ to $V_{EE}$ $I_{I/O} = 0.1\text{mA}$	70	170		200			$\Omega$	
		4.5	-4.5		50	85		105				
		6.0	-6.0		30	70		85				
		2.0	GND		120	180		215				
		4.5	GND		50	80		100				
		4.5	-4.5		35	60		75				
		6.0	-6.0		20	40		60				
$\Delta R_{ON}$	Difference of ON Resistance between switches	4.5	GND	$V_{IN} = V_{IHC}$ or $V_{ILC}$ $V_{I/O} = V_{CC}$ to $V_{EE}$ $I_{I/O} = 0.1\text{mA}$	10	15		20			$\Omega$	
		4.5	-4.5		5	10		15				
		6.0	-6.0		5	10		15				
$I_{OFF}$	Input/Output Leakage Current (SWITCH OFF)	6.0	GND	$V_{OS} = V_{CC}$ or GND $V_{IS} = V_{CC}$ or GND $V_{IN} = V_{IHC}$ or $V_{ILC}$			$\pm 0.06$		$\pm 0.6$	$\pm 2$	$\mu A$	
		6.0	-6.0				$\pm 0.1$		$\pm 1$	$\pm 2$		
$I_{IZ}$	Switch Input Leakage Current (SWITCH ON, OUTPUT OPEN)	6.0	GND	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IHC}$ or $V_{ILC}$			$\pm 0.06$		$\pm 0.6$	$\pm 2$	$\mu A$	
		6.0	-6.0				$\pm 0.1$		$\pm 1$	$\pm 2$		
$I_{IN}$	Control Input Current	6.0	$V_I = V_{CC}$ or GND			$10^{-5}$	$\pm 0.1$		$\pm 1$	$\pm 1$	$\mu A$	

## M74HC4316

### AC ELECTRICAL CHARACTERISTICS ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6\text{ns}$ )

Symbol	Parameter	Test Condition			Value						Unit	
		$V_{CC}$ (V)	$V_{EE}$ (V)		$T_A = 25^\circ\text{C}$			$-40 \text{ to } 85^\circ\text{C}$		$-55 \text{ to } 125^\circ\text{C}$		
					Min.	Typ.	Max.	Min.	Max.	Min.		
$\Phi_{I/O}$	Phase Difference Between Input and Output	2.0	GND			12	30		40		ns	
		4.5	GND			3	6		8			
		6.0	GND			3	5		7			
		4.5	-4.5			2	4		5			
		6.0	-6.0			2	4		5			
$t_{PZL}$ $t_{PZH}$	Output Enable Time (E, C - OUT)	2.0	GND	$R_L = 1\text{K}\Omega$		56	115		145		ns	
		4.5	GND			14	23		29			
		6.0	GND			12	20		25			
		4.5	-4.5			13	21		26			
		6.0	-6.0			11	18		23			
$t_{PLZ}$ $t_{PHZ}$	Output Disable Time (E, C - OUT)	2.0	GND	$R_L = 1\text{K}\Omega$		112	205		255		ns	
		4.5	GND			28	41		51			
		6.0	GND			24	35		43			
		4.5	-4.5			24	34		43			
		6.0	-6.0			21	29		36			
$f_{MAX}$	Maximum Control Input Frequency	2.0	GND	$R_L = 1\text{K}\Omega$ $C_L = 15 \text{ pF}$ $V_{OUT} = 1/2 V_{CC}$		2					MHz	
		4.5	GND			9						
		6.0	GND			11						

### CAPACITIVE CHARACTERISTICS

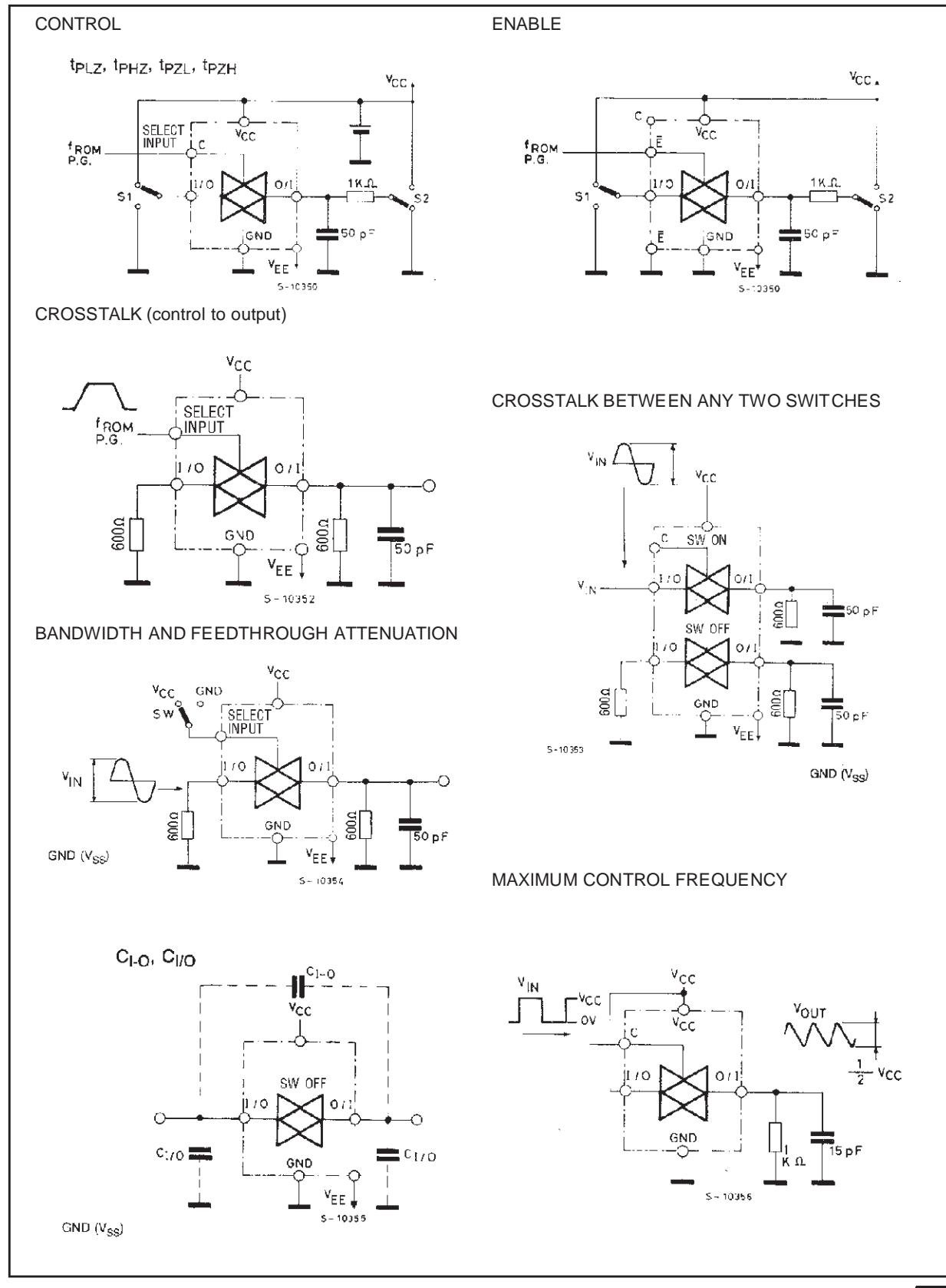
Symbol	Parameter	Test Condition			Value						Unit	
		$V_{CC}$ (V)			$T_A = 25^\circ\text{C}$			$-40 \text{ to } 85^\circ\text{C}$		$-55 \text{ to } 125^\circ\text{C}$		
					Min.	Typ.	Max.	Min.	Max.	Min.		
$C_{IN}$	Input Capacitance					5	10		10		10 pF	
$C_{I/O}$	Switch Terminal Capacitance	4.5	-4.5			5					pF	
$C_{IOS}$	Feed Through Capacitance	4.5	-4.5			1					pF	
$C_{PD}$	Power Dissipation Capacitance (note 1)	5.0	GND		16						pF	

1)  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC(\text{opr})} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

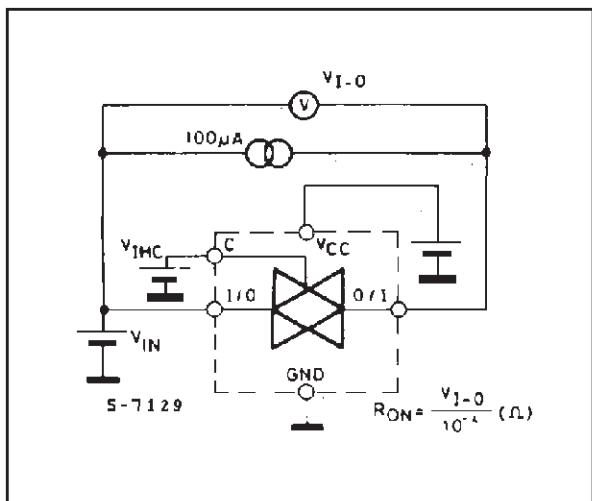
ANALOG SWITCH CHARACTERISTICS (GND = 0V; T<sub>A</sub> = 25°C)

Symbol	Parameter	Test Condition				Value	Unit		
		V <sub>CC</sub> (V)	V <sub>EE</sub> (V)	V <sub>IN</sub> (V <sub>p-p</sub> )		Typ.			
	Sine Wave Distortion (THD)	2.25	2.25	4	$f_{IN} = 1 \text{ KHz}$ $R_L = 10 \text{ K}\Omega$ , $C_L = 50 \text{ pF}$	0.025	%		
		4.5	4.5	8		0.020			
		6.0	6.0	11		0.018			
f <sub>MAX</sub>	Frequency Response (Switch ON)	2.25	2.25	Adjust f <sub>IN</sub> voltage to obtain 0 dBm at V <sub>OS</sub> . Increase f <sub>IN</sub> Frequency until dB meter reads -3dB			MHz		
		4.5	4.5	$R_L = 50\Omega$ , $C_L = 10 \text{ pF}$ , $f_{IN} = 1\text{MHz}$ sine wave					
		6.0	6.0						
	Feed through Attenuation (Switch OFF)	2.25	2.25	V <sub>IN</sub> is centered at V <sub>CC</sub> /2. Adjust input for 0 dBm			dB		
		4.5	4.5	$R_L = 600\Omega$ , $C_L = 50 \text{ pF}$ , $f_{IN} = 1\text{MHz}$ sine wave					
		6.0	6.0						
	Crosstalk (Control Input to Signal Output)	2.25	2.25	$R_L = 600\Omega$ , $C_L = 50 \text{ pF}$ , $f_{IN} = 1\text{MHz}$ square wave ( $t_r = t_f = 6\text{ns}$ )			mV		
		4.5	4.5						
		6.0	6.0						
	Crosstalk (Between Any Switches)	2.25	2.25	Adjust V <sub>IN</sub> to Obtain 0 dBm at input			dB		
		4.5	4.5	$R_L = 600\Omega$ , $C_L = 50 \text{ pF}$ , $f_{IN} = 1\text{MHz}$ sine wave					
		6.0	6.0						

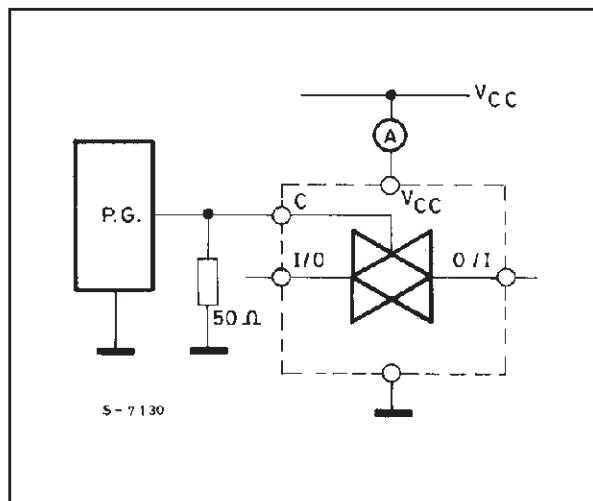
**SWITCHING CHARACTERISTICS TEST CIRCUIT**



CHANNEL RESISTANCE ( $R_{ON}$ )

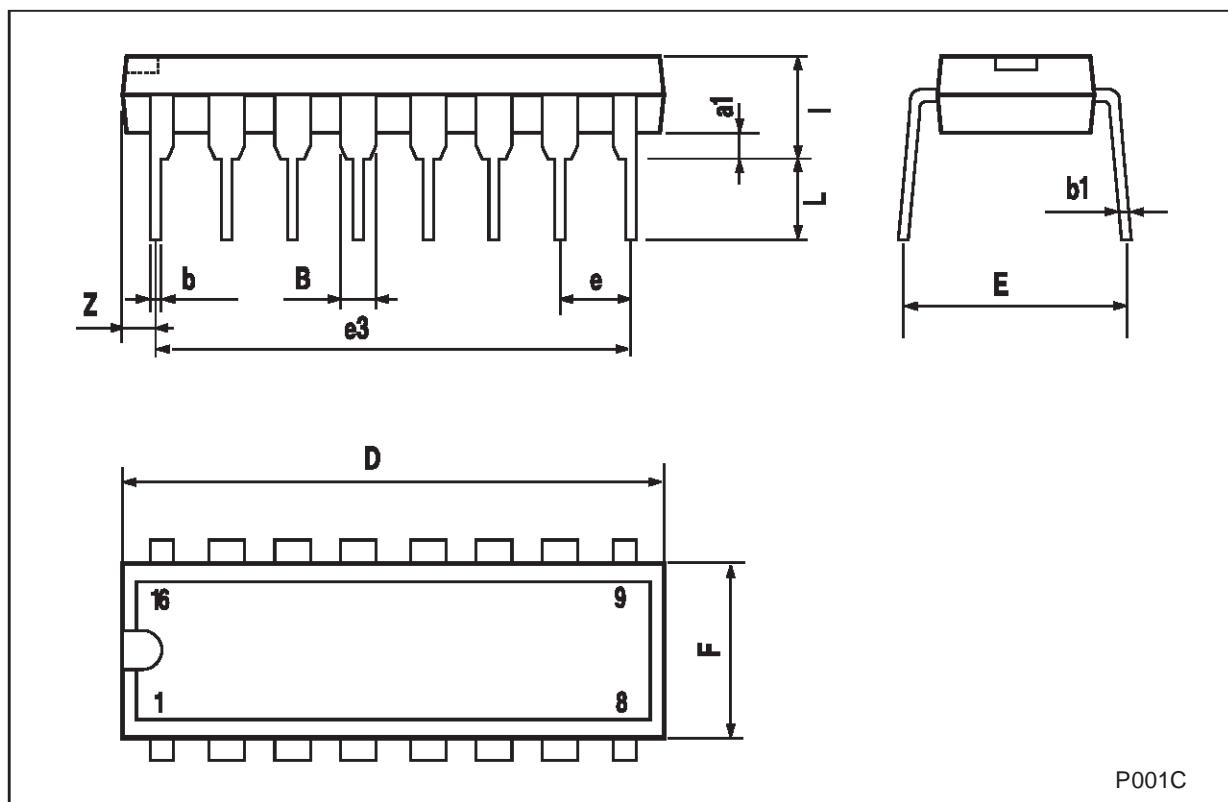


$I_{CC}$  (Opr.)



## Plastic DIP-16 (0.25) MECHANICAL DATA

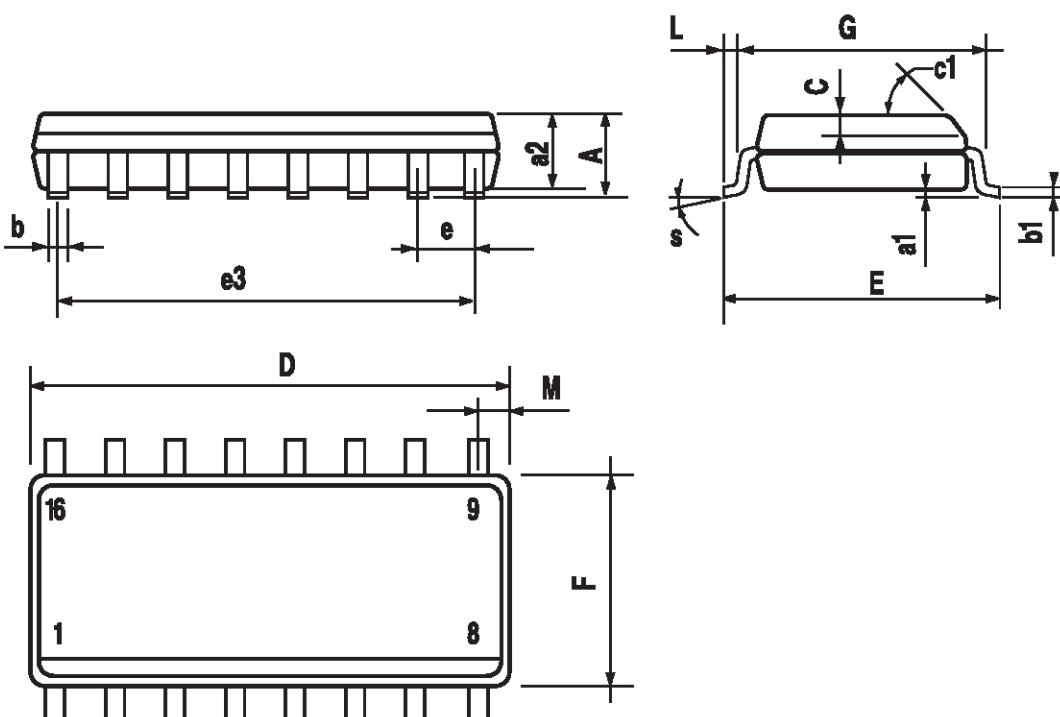
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



P001C

## SO-16 MECHANICAL DATA

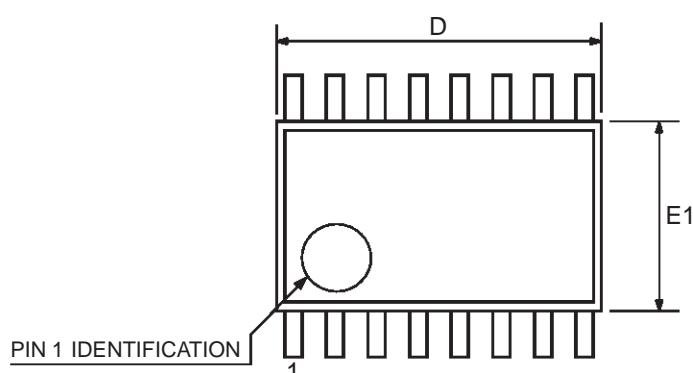
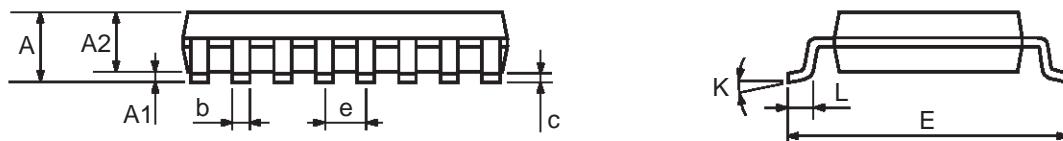
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1		45° (typ.)				
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S		8° (max.)				



PO13H

## TSSOP16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



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